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### COMMUNICATION

# Voltage Output of Efficient Perovskite Solar Cells with high Open-Circuit Voltage and Fill Factor

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Besides the generated photocurrent as a key factor that impacts the efficiency of solar cells, the produced photovoltage and fill factor are also of critical importance. Therefore, understanding and optimization of the opencircuit voltage (Voc) of perovskite solar cells, especially with a architecture consisting of mesoporous (mp)-TiO<sub>2</sub>/perovskite/hole transporting materials (HTMs), are required to further improve the conversion efficiency. In this work, we study the effects of the energy level between CH<sub>3</sub>NH<sub>3</sub>(=MA)PbI<sub>3</sub> and MAPbBr<sub>3</sub> and a series of triarylamine polymer derivatives containing fluorene and indenofluorene, which have different highest occupied molecular orbital (HOMO) levels, in terms of the photovoltaic behaviour. The voltage output of the device is found to be dependent on the higher energy level of perovskite solar absorbers as well as the HOMO level of the HTMs. The combination of MAPbBr3 and a deep-HOMO HTM leads to a high photovoltage of 1.40 V, with fill factor of 79% and an energy conversion efficiency of up to 6.7%, which is the highest value reported till date for MAPbBr3 perovskite solar cells.

Efficient and inexpensive energy harvesting by solar cells is a great challenge for the 21st century in the field of renewable energy. Most recently, inorganic–organic hybrid solar cells have been demonstrated to be amongst the most promising of emerging photovoltaic devices with respect to the power conversion efficiency (PCE), use of liquid-free hole-conductors as charge carriers, abundant availability, and inexpensive fabrication.<sup>1-8</sup> Mesoscopic inorganic–organic hybrid heterojunction solar cells consisting of Sb<sub>2</sub>S<sub>3</sub> or combined Sb<sub>2</sub>S<sub>3</sub> and Sb<sub>2</sub>Se<sub>3</sub> as light harvesters have shown a PCE of 3-7.5%.<sup>1-4</sup> Inorganic light harvesters in these cells have a high potential to further improve the performance as compared to the conventional dyes, owing to benefits such as high extinction coefficients, large intrinsic dipole moments, and easily tuneable band-gaps.<sup>9</sup> A breakthrough in PCE for inorganic–organic

hybrid solar cells has been achieved by the introduction of organolead trihalide perovskites as light harvesters.<sup>5-8</sup> Previously, these perovskites were used for light absorption in dye-sensitized solar cells with liquid electrolytes, which exhibit a low PCE.<sup>10-11</sup> However, the photovoltaic (PV) efficiency of the perovskite-based solar cells could be greatly improved by the use of a spiro-OMeTAD-based or polymeric solid hole-conductor.<sup>5-8</sup> The PCE was further improved by the sequential process of PbI<sub>2</sub> and CH<sub>3</sub>NH<sub>3</sub>I (methylammonium iodide: MAI) to deposit CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3</sub> (=MAPbI<sub>3</sub>) perovskites on a mesoporous (mp)-TiO<sub>2</sub> electrode,<sup>12</sup> and planar thin layer of MAPbI<sub>3-x</sub>Cl<sub>x</sub> was deposited by the vacuum thermal evaporation method without the mp-TiO<sub>2</sub> electrode.<sup>13</sup>

In addition, the perovskite was justifiably utilized as a donor in organic photovoltaic architectures because of its large diffusion length.<sup>14,15</sup> Thus, the unusual properties of the perovskites could be exploited for thin-film planar, mesosuperstructured, or mesoporous architectures in perovskitesensitized solar cells. However, we recently proposed that a bilayer architecture consisting of the perovskite-infiltrated mp-TiO<sub>2</sub> and pure perovskite is crucial in fabricating efficient perovskite cells with coincident reverse and forward scans.<sup>16</sup>

Generally, high open-circuit voltage ( $V_{oc}$ ) solar cells are important tools for driving electrochemical reactions or adopting new device architectures, such as the top-cell in tandem solar cell structures. Hodes and co-workers<sup>17</sup> demonstrated a high  $V_{oc}$  of 1.5 V from a solar cell based on the organic-inorganic lead bromide and 4,4'-bis(N-carbazolyl)-1,1'biphenyl (CBP) hybrid structure, but the efficiency was low. J. Qiu et al.<sup>18</sup> described organolead halide perovskite cells, with CH<sub>3</sub>NH<sub>3</sub>PbBr<sub>3</sub> as the light harvester and poly[*N*-90heptadecanyl-2,7-carbazole-alt-3,6-bis-(thiophen-5-yl)-2,5dioctyl-2,5-dihydropyrrolo[3,4]pyrrole-1,4-dione] (PCBTDPP) as the hole transporting material (HTM), which showed a  $V_{oc}$  of 1.16 V and efficiency of 3.04%, which is the highest observed

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for solid state MAPbBr<sub>3</sub> devices to date. Nevertheless, to the best of our knowledge, MAPbBr3 perovskite solar cells that have PCEs exceeding 6% with a Voc approaching 1.4 V have not yet been reported. It is necessary to determine how and where the V<sub>oc</sub> is established for understanding PV performance and its optimization. In particular, the origin of Voc in the architecture consisting bilaver cell of mp-TiO<sub>2</sub>perovskite/perovskite/HTM, which is significantly different from conventional dye-sensitized solar cells, is poorly understood. A high Voc in the perovskite solar cell can be achieved by matching and judiciously selecting the perovskite lead halide-based absorber and the HTMs.

Here, we investigated the effect of lowering the highest occupied molecular orbital (HOMO) of the HTM to enhance the  $V_{oc}$  of mesoscopic perovskite solar cells. We found that a deeper HOMO results in a significantly larger  $V_{oc}$ , which enabled us to fabricate high-efficiency solar cells with a  $V_{oc}$  of up to 1.40 V and fill factor (FF) of 79% as well as PCE of 6.7 %, the highest values ever reported for MAPbBr<sub>3</sub>perovskite solar cells.



Fig. 1 (a) Molecular structure of HTMs (PTAA, PF8-TAA, and PIF8-TAA); (b) PESA spectra of perovskite films (MAPbI<sub>3</sub>, MAPbBr<sub>3</sub>) and HTM films on fused silica substrate; (c) energy band diagram for TiO<sub>2</sub>, perovskite materials (MAPbI<sub>3</sub>, MAPbBr<sub>3</sub>), and HTMs.

Inorganic-organic hybrid solar cells were fabricated in the configuration mesoporous (mp)-TiO2/perovskite/HTM/Au. Both the light absorber (MAPbBr3 or MAPbI3 perovskites) and the HTM were deposited onto mp-TiO<sub>2</sub> by spin coating. The homogeneous perovskite layer was deposited with full coverage on mp-TiO<sub>2</sub> (see Fig. S1) The HTMs used in this work are triarylamine (TAA) polymer derivatives containing fluorene and indenofluorene, named P-TAA, PF8-TAA, and PIF8-TAA; the molecular structures of these are shown in Fig. 1a.<sup>19</sup> First, we measured the valence bands of MAPbBr3 and MAPbI3 perovskites, and the HOMO levels of HTMs, which are P-TAA, PF8-TAA, and PIF8-TAA, because the  $V_{oc}$  in solar cell devices can be derived from the quasi-Fermi levels of each material in the structure. Fig. 1b shows the photoelectron emission spectra for MAPbI<sub>3</sub>, MAPbBr<sub>3</sub>, PTAA, PF8-TAA, and PIF8-TAA obtained using a Riken Keiki AC-2 photoelectron spectrometer. Photoelectron spectroscopy (PES) measurements were successfully

performed to measure the occupied electronic states of an organic semiconductor and the valance band edges (VBEs) in solids.<sup>20-22</sup> The measured VBEs of MAPbI<sub>3</sub> and MAPbBr<sub>3</sub> were -5.46 eV, which is in accord with the reported values,<sup>6</sup> and -5.68 eV, respectively. The HOMO levels of P-TAA, PF8-TAA, and PIF8-TAA were measured to be -5.14 eV, -5.44 eV, and -5.51 eV which are in accord with a previous report.<sup>19</sup> The band alignment is represented in Fig. 1c, where the conduction band edge is calculated from the optical band gap of the perovskite materials. The excited state of the perovskite is higher than the TiO<sub>2</sub> conduction band, and the HOMO levels of PF8-TAA and PIF8-TAA are located near the valance band edges of MAPbI<sub>3</sub> and MAPbBr3, respectively.



Fig. 2. (a) Diffused reflectance spectrum of FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>: MAPbBr<sub>3</sub>/Au specimen; (b) *J-V* characteristics for FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>:MAPbBr<sub>3</sub>/HTM/Au, where HTMs are PTAA, PF8-TAA, and PIF8-TAA; (c) EQE spectra; (d) *J-V* characteristics for FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>:MAPbI3/HTM/Au with these three HTMs.

Fig. 2a shows the diffuse reflectance of MAPbBr<sub>3</sub> deposited on mp-TiO<sub>2</sub>/blocking layer (bl)-TiO<sub>2</sub>/FTO substrate, which was measured using a UV-Vis spectrometer with an integrated sphere. The optical band gap of MAPbBr3 is calculated to be 2.3 eV from the diffuse reflectance spectra. Fig. 2b shows the J-V characteristics of the FTO/bl-TiO2/mp-TiO2:MAPbBr3/HTM-devices with different HTMs of PTAA, PF8-TAA, and PIF8-TAA measured under AM 1.5 illumination conditions. Table 1 summarizes the extracted shortcircuit current density  $(J_{sc})$ ,  $V_{oc}$ , and fill factor (FF).  $V_{oc}$  increased with the deeper HOMO of the HTMs, from 1.29 V of P-TAA to 1.36 V of PF8-TAA and 1.40 V of PIF8-TAA. This reveals that the HOMO level of the HTM influences  $V_{oc}$ . The origin of  $V_{oc}$  in perovskite solar cells is typically described by the difference between the lowest unoccupied molecular orbital (LUMO) level of the perovskite and the HOMO of the HTM, or by the potential difference between the quasi-Fermi level of the electron (E<sub>fn</sub>) at the electron extracting layer/anode interface and the quasi-Fermi level of Journal Name

the hole (E<sub>fp</sub>) at the hole extracting layer/cathode interface under illumination, assuming that recombination within the device can be ignored.<sup>18,23</sup> Therefore, the high  $V_{oc}$  of 1.40 V in MAPbBr<sub>3</sub>-PIF8(TAA)-device is ascribed to the deeper HOMO level near the VBE of MAPbBr<sub>3</sub>. The determination of V<sub>oc</sub> in the perovskite cell will be further discussed later. In Fig. 2b and Table 1, we also see that the increased V<sub>oc</sub> accompanies a decrease in the photocurrent (Jsc), while the FF increases, in the sequence P-TAA, PF8-TAA, and PIF8-TAA. The external quantum efficiency (EQE) shown in Fig. 2c for devices using PIF-TAA and PIF8-TAA as HTMs is lower than that of P-TAA over the whole range of absorption wavelengths. The relatively low EQE and decreased Jsc with deeper HOMO levels of the HTMs might be attributed to the lowering of the driving force for charge injection, due to the small disruption in energy levels between the VBE of MAPbBr3 and the HOMO of the HTM, as shown in Fig. 1b. On the contrary, the remarkable FF in PIF8-TAA can be related to the charge carrier mobility (4 x  $10^{-2}$  cm<sup>2</sup>/V. s) which is higher than that of PF8-TAA ( $2 \times 10^{-2} \text{ cm}^2/\text{V}$ . s) and P-TAA  $(4 \times 10^{-3} \text{ cm}^2/\text{V. s})$ .<sup>19</sup> Much larger driving force of P-TAA may counterbalance the low charge carrier mobility, resulting in the same FF with PF8-TAA. However, FF might also be determined by other factors such as charge injection rate and recombination rate at interface contact between perovskite and HTM.<sup>24</sup> Regardless of the reduced Jsc, the increase in Voc and FF leads to an improved PCE of 6.7%. Consequently, the Voc FF, and PCE of 1.40 V, 79%, and 6.7%, respectively, are the highest among those reported for existing single-junction MAPbBr3 perovskite solar cells. To ensure the reproducibility of the results, histogram for the efficiencies of each cell was shown in Fig. S2.

Table 1. Photovoltaic parameters for  $MAPbI_3$  and  $MAPbBr_3$  perovskite solar cells using PTAA, PF8-TAA, and PIF8-TAA as HTMs

Perovskite	HTMs	Jsc (mA/cm <sup>2</sup> )	Voc (V)	FF	PCE (%)
MAPbBr <sub>3</sub>	PTAA	6.6	1.29	0.70	5.9
	PF8- TAA	6.3	1.36	0.70	6.0
	PIF8- TAA	6.1	1.40	0.79	6.7
MAPbI <sub>3</sub>	PTAA	21.3	1.04	0.73	16.2
	PF8- TAA	8.9	0.92	0.56	4.6
	PIF8- TAA	19.0	1.04	0.46	9.1

For the perovskite solar cell, especially for the architecture consisting of the mp-TiO<sub>2</sub>/perovskite composite and pure perovskite layers, our previous results<sup>7.8</sup> suggested that the  $V_{oc}$  is not simply determined by the difference between the electron Fermi level at mp-TiO<sub>2</sub> and the hole Fermi level at the HTM. Under the current operation mechanism, the perovskite acts as an absorber as well as charge (either electron or hole) carrier; hence, the voltage output is expected to be high since sensitization or donor-acceptor type devices significantly reduce the expectable  $V_{oc}$  because of some charge transfer energy loss. Furthermore, perovskite has high capacitance and can accumulate charges on itself, because of which the quasi Fermi level is controlled upon illumination.<sup>25</sup>

To gain more insight into the V<sub>oc</sub> of the perovskite cells with HTMs having a deeper HOMO, we additionally fabricated devices using MAPbI<sub>3</sub> with the same HTMs used in MAPbBr<sub>3</sub>. Fig. 2d shows the J-V characteristics for MAPbI3 perovskite solar cells using PTAA, PIF8-TAA, and PIF8-TAA as the HTM; the photovoltaic parameters are also summarized in Table 1. One can assume that  $E_{fn}$ is constant in FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>:perovskite/HTM-devices, although different HOMO levels of HTMs are used. It is noted that the HOMO levels of PTAA and PF8-TAA are -5.14 eV and -5.44 eV, respectively, which are higher than the VBE (-5.46 eV) of MAPbI<sub>3</sub> and therefore, hole transport from MAPbI<sub>3</sub> to the HTMs is favoured. However, PIF8-TAA has a lower HOMO level of -5.51 eV as compared to the VBE of MAPbI<sub>3</sub>, which may result in a holeinjection barrier between MAPbI3 and PIF8-TAA. The J-V curve of the FTO/bl-TiO2/mp-TiO2:MAPbI3/PIF8-TAA-device shows the roll-over effect, in which the current is saturated at high forward bias, while the PTAA and PF8-devices show a typical J-V response. The roll-over effect has been explained by a back contact holeinjection barrier in CdTe, PbS, and organic solar cells.<sup>26</sup> Moreover, the driving force might be not enough for hole injection from MAPbI<sub>3</sub> to PF8-TAA because PF8-TAA has a similar HOMO level as the VBE in MAPbI<sub>3</sub>, as shown in Fig. 1b. Therefore, it is difficult to discuss the effect of the HOMO level in HTMs on  $V_{oc}$  for MAPbI<sub>3</sub>-devices, because of the insufficient driving force for charge injection and the abnormality in the J-V response. Nevertheless, the significantly high Jsc value of 19.0 mA/cm<sup>2</sup> for FTO/bl-TiO<sub>2</sub>/mp-TiO2:MAPbI3/PIF8-TAA-device in spite of the unfavourable energetic alignment between MAPbI3 and PIF8-TAA is an interesting result. Other effects except the energy level between perovskite and the HTM may affect charge transfer, because the perovskite material is known for its very low exciton binding energy or its ability to act as a free electron-hole carrier.<sup>27</sup>



Fig 3. (a) *J-V* characteristics for MAPbI<sub>3</sub>-PTAA, and MAPbBr<sub>3</sub>-PTAA devices. Insert shows a cross-sectional SEM image of the bi-layer architecture device (FTO/bl-TiO<sub>2</sub>/mp-TiO<sub>2</sub>:MAPbBr<sub>3</sub>/PTAA/Au). (b) Schematic of the bi-layered device architecture and its energy band diagram.  $E_{fn}$  and  $E_{fp}$  are the electron and hole quasi-Fermi levels, which are determined by the interaction between TiO<sub>2</sub> and the perovskite and between the perovskite and the HTM, respectively.

*J-V* characteristics and photovoltaic parameters of MAPbI<sub>3</sub> and MAPbBr<sub>3</sub> fabricated with spiro-OMeTAD [(2,2',7,7'-tetrakis(N,N-di-p-methoxyphenylamine) -9,9'-spirobifluorene)] as low-

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molecular HTM were given in Fig. S3 and table S1. We see that the use of spiro-MeOTAD, which has higher HOMO level than that of PTAA, resulted in a decrease of the  $V_{oc}$  for both MAPbI<sub>3</sub> and MAPbBr<sub>3</sub>. Therefore, our results further suggest that the energy level of the contact materials could have a strong impact on the deliverable energy of photoinduced charges. However, it is important to select energetically favourable contact materials with the HOMO well-aligned to the VBE of the perovskite to maximize the energy output.

Fig. 3a compares the J-V characteristics for MAPbI<sub>3</sub> and MAPbBr<sub>3</sub> perovskite solar cells using PTAA as the HTM. The cross-sectional image of a representative device is inserted in Fig. 3a. In comparison of the Voc value for FTO/bl-TiO2/mp-TiO<sub>2</sub>:MAPbBr<sub>3</sub>/PTAA with that of FTO/bl-TiO<sub>2</sub>/mp-TiO2:MAPbI3/PTAA, the Voc can be increased from 1.04 V to 1.29 V simply by changing the perovskite material from MAPbI<sub>3</sub> to MAPbBr<sub>3</sub> in the same sandwich structure between mp-TiO<sub>2</sub> and PTAA. This result reveals that the perovskite materials obviously contribute to  $E_{fn}$  and  $E_{fp}$  within the device. As shown in Fig. 1b, MAPbBr<sub>3</sub>, with a wider band gap (2.3 eV) than MAPbI<sub>3</sub> (1.55eV), has a lower VBE (5.68 eV) and a higher conduction band edge (CBE, 3.38 eV) as compared to MAPbI<sub>3</sub>. Therefore, when  $E_{fn}$  and  $E_{fp}$  are built-up within the device under light illumination, MAPbBr3 might lead to a larger difference between E<sub>fn</sub> and E<sub>fp</sub> as compared to MAPbI<sub>3</sub>, in spite of using the same electron (TiO<sub>2</sub>) and hole extracting layers (PTAA), thus resulting in higher V<sub>oc</sub>. This is not expected in sensitized solar cells, because the FTO/bl-TiO2/mp-TiO<sub>2</sub>:MAPbBr<sub>3</sub>/PTAA/Au device shows a higher V<sub>oc</sub> of 1.29 V than the potential difference (1.16 eV) between the CBM (-4.0 eV) of TiO<sub>2</sub> and the HOMO level (-5.16 eV) of PTAA. Consequently, as depicted in Fig. 3b, the CBE level of the MAPbBr<sub>3</sub> can manipulate the voltage output of mp-TiO<sub>2</sub>perovskite/perovskite/HTM bilayer junction cell. Based on this reasoning, a remarkably high voltage (1.40 V) device has been realized by judicious selection of the perovskite and HTM. This also means the energy gap with charge separation significantly dominates the voltage output.

#### Summary

In summary, we have fabricated mp-TiO<sub>2</sub>/MAPbI<sub>3</sub> and MAPbI<sub>3</sub> perovskite as the light harvester, and P-TAA, PF8-TAA, PIF-TAA as HTMs. The V<sub>oc</sub> in MAPbBr<sub>3</sub> perovskite cells was increased from 1.29 V of P-TAA to 1.36 V of PF8-TAA and 1.40 V of PIF8-TAA with a deeper HOMO level. In addition, the V<sub>oc</sub> was decreased from 1.29 V to 1.04 V by using MAPbI<sub>3</sub> in the place of MAPbBr<sub>3</sub> with the same configuration and HTM (PTAA). This result reveals that both the perovskite device displayed a remarkably higher Voc of 1.40 V, with an FF of 79%, due to the deep HOMO level and superior hole mobility, as well as a high PCE to 6.7%, when PIF8-TAA was used as the HTM. The present study demonstrates the main roles of the HTMs and perovskite light harvester in determining the Voc and

provides a suitable strategy for the design and development of perovskite-based solar cells showing a high  $V_{oc}$ , FF, and significantly improved PCE.

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### TOC

The voltage output of perovskite solar cells is found to be dependent on both energy level of perovskite itself as solar absorber and the hole transporting materials.

